



D1213A-04TS

4 CHANNEL LOW CAPACITANCE TVS DIODE ARRAY

Features

- IEC 61000-4-2 (ESD): Air ±15kV, Contact ±8kV
- 4 Channels of ESD Protection
- Low Channel Input Capacitance of 0.85pF Typical
- Typically Used at High Speed Ports such as USB 2.0, IEEE1394, Serial ATA, DVI, HDMI, PCI
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

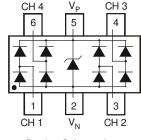
Mechanical Data

- Case: TSOT26
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish annealed over Copper leadframe (Lead Free Plating) Solderable per MIL-STD-202, Method 208 👀
- Weight: 0.013 grams (approximate)



TSOT26

Top View



Device Schematic

Ordering Information (Note 4)

Part Number	Case	Packaging
D1213A-04TS-7	TSOT26	3000/Tape & Reel

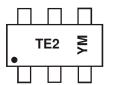
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and

 Halogen- and Antimony-free "Green <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com.

Marking Information



TE2 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: Z = 2012) M = Month (ex: 9 = September)

	Date	Code	Key
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Duie Code Rey												
Year	201	1	2012		2013	20	14	2015		2016	2	2017
Code	Y		Z		А	E	3	С		D		E
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	Conditions
Operating Supply Voltage	V _P - V _N	6.0	V	-
DC Voltage at any Channel Input	-	(V _N – 0.5) to (V _P + 0.5)	V	-
Peak Pulse Current	IPP	5	A	8/20µs, Per Figure 3
ESD Protection – Contact Discharge	V _{ESD_Contact}	±8	kV	Standard IEC 61000-4-2
ESD Protection – Air Discharge	V _{ESD Air}	±15	kV	Standard IEC 61000-4-2

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	300	mW
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	417	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions
Operating Supply Voltage	VP	-	3.3	5.5	V	-
Operating Supply Current (Note 6)	Ι _Ρ	-	-	8.0	μΑ	$(V_{P} - V_{N}) = 3.3V$
Channel Leakage Current (Note 6)	I _R	-	0.1	1.0	μA	$V_{P} = 5V, V_{N} = 0V$
Reverse breakdown voltage	VBR	6.0	-	-	V	I _R = 1mA
Clamping Voltage, Positive Transients	V _{CL1}	-	10.0	-	V	I _{PP} = 1A (Note 7)
Clamping Voltage, Negative Transients	V _{CL2}	-	-1.7	-	V	I _{PP} = -1A (Note 7)
Forward Voltage for Top Diode	V _{FD1}	0.60	0.80	0.95	V	$I_F = 8mA$, any channel to V_P
Forward Voltage for Bottom Diode	V _{FD2}	0.60	0.80	0.95	V	$I_F = 8mA$, V_N to and channel
Dynamic Resistance	R _{DYN}	-	0.9	-	Ω	I _{PP} = 1A (Note 7)
Channel Input Capacitance	Ст	-	0.85	1.2	pF	$V_{IN} = 1.65V, V_P = 3.3V,$ $V_N = 0V, f = 1MHz$

5. Device mounted on FR-4 PCB pad layout (2oz copper) as shown on Diodes, Inc. suggested pad layout AP02001, which can be found on our website at http://www.diodes.com.

6. Short duration pulse test used to minimize self-heating effect.

7. Clamping voltage value is based on an $8x20\mu s$ peak pulse current (I_{pp}) waveform.

8. Measured from any channel to V_{N} .

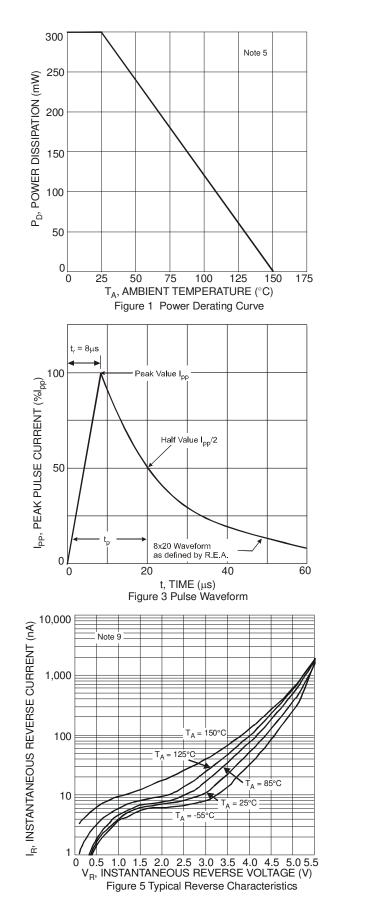
9. Measured from VP to VN.

Notes:

10. For information on the impact of Diodes' USB 2.0 compatible ESD protectors on signal integrity including eye diagram plots, please refer to AN77 at the following URL: http://www.diodes.com/destools/appnote_dnote.html.



NEW PRODUCT



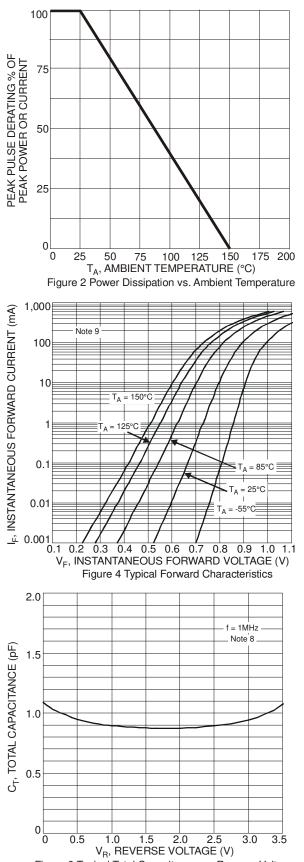
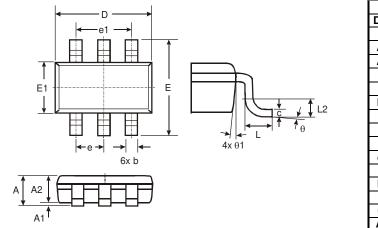


Figure 6 Typical Total Capacitance vs. Reverse Voltage



Package Outline Dimensions

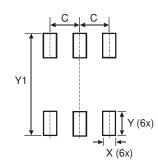
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



Dim	Min	Max	Тур
Α		1.00	_
A1	0.01	0.10	_
A2	0.84	0.90	_
D	-	-	2.90
Ε	-	1	2.80
E1	-	-	1.60
b	0.30	0.45	-
С	0.12	0.20	_
е	-	-	0.95
e1	-	-	1.90
L	0.30	0.50	
L2	_	-	0.25
θ	0°	8°	4°
θ1	4°	12°	-
All D	imensi	ons in	mm

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	0.950
Х	0.700
Y	1.000
Y1	3.199



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